

/ Descriptions

Dual P-Channel MOSFET in a SOT23-6 Plastic Package.

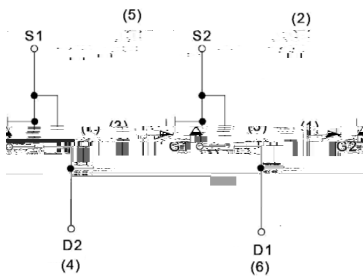
/ Features

Super high dense cell design for low $R_{DS(ON)}$, Rugged and reliable. HF product.

/ Applications

Power Management in Notebook computer, Portable Equipment and Battery powered systems.

/ Equivalent Circuit



/ Pinning



PIN1 G1 PIN 2 S2 PIN 3 G2

PIN 4 D2 PIN 5 S1 PIN 6 D1

/ Marking

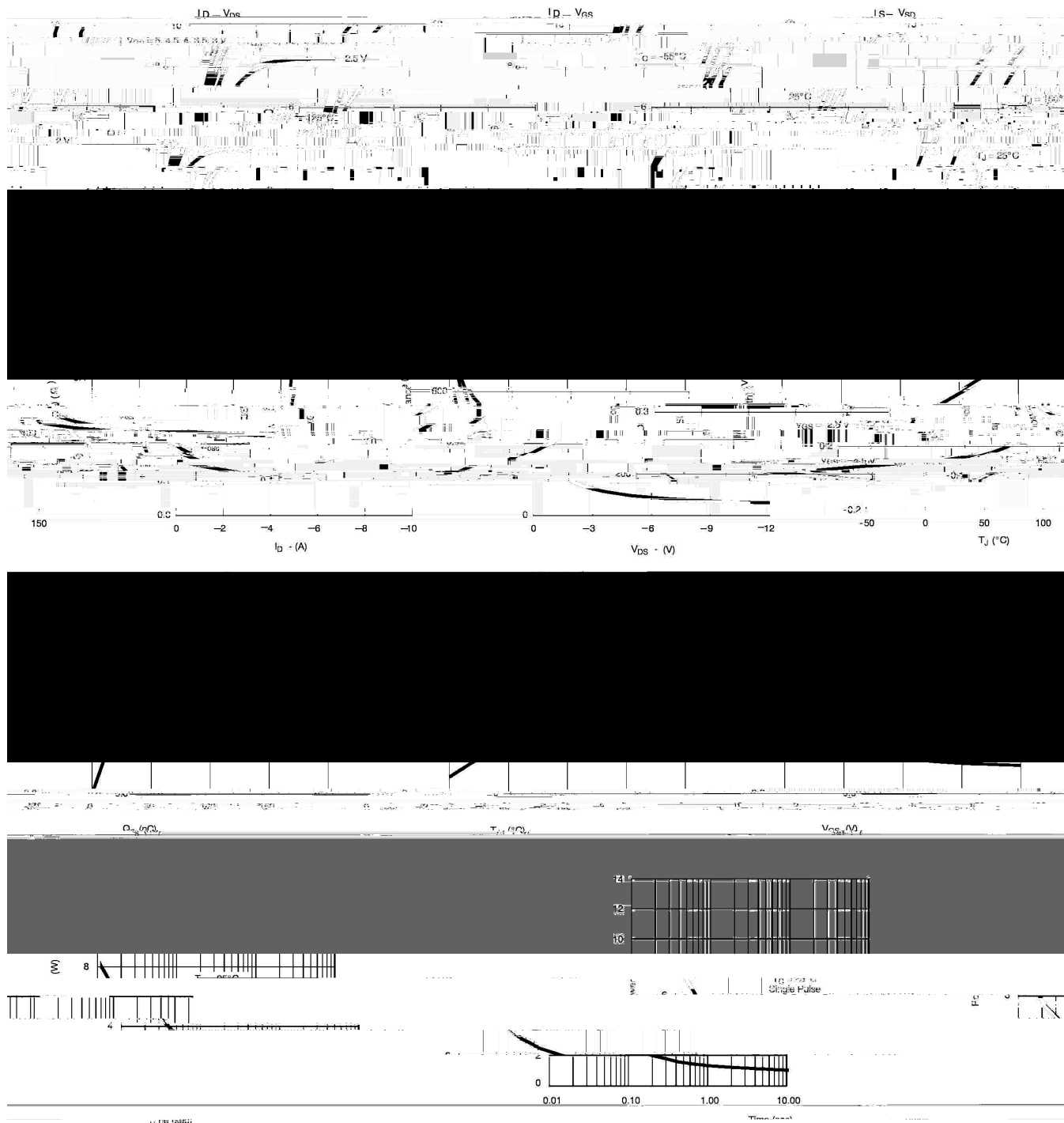
See Marking Instructions

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DSS}	-20	V
Gate-Source Voltage	V_{GSS}	± 12	V
Continuous Drain Current	I_D^*	-3.0	A

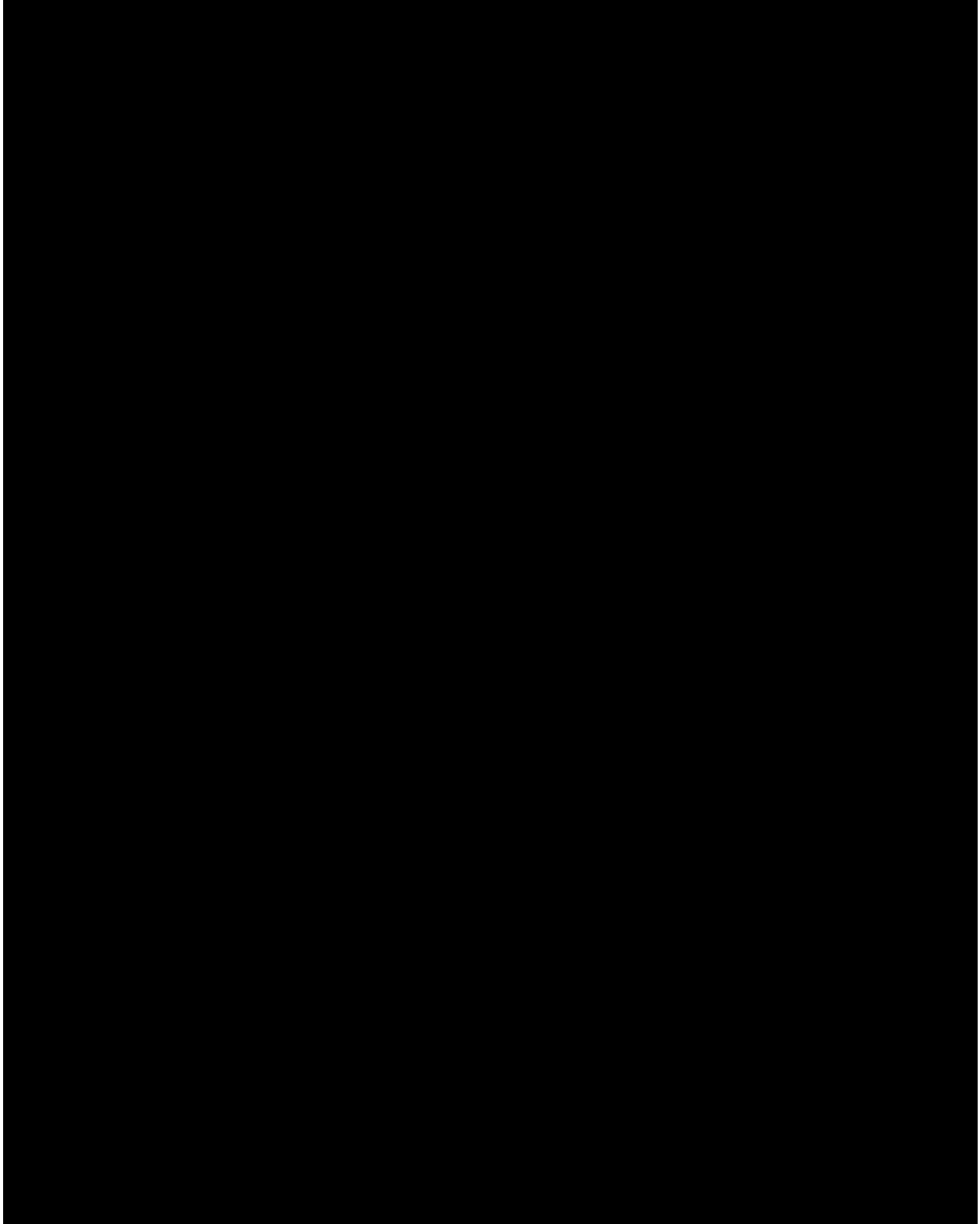
/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ
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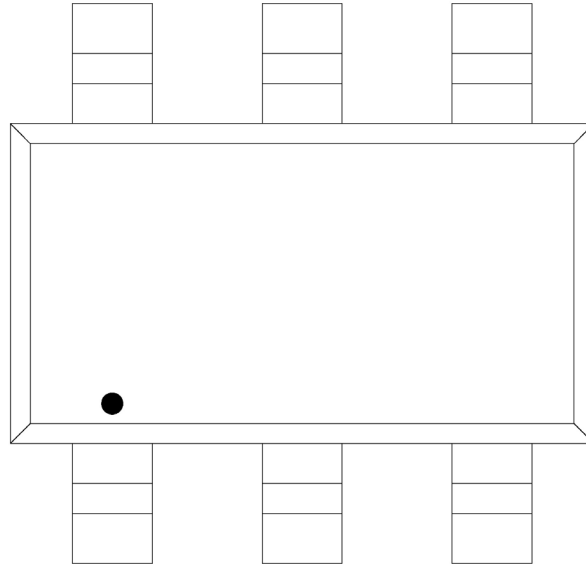
/ Electrical Characteristic Curve



/ Package Dimensions

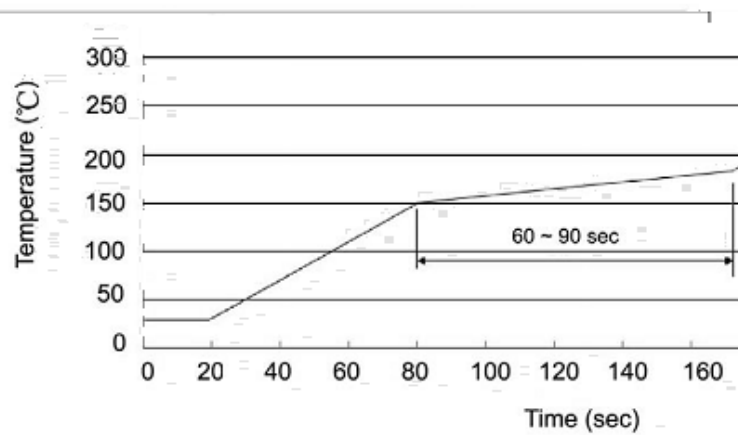


/ Marking Instructions



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Up shrdwxrh Prr iioh i rr IU Uhi orw Vroghriqj +Pe-Frhh,



Note:

- 60 ~ 90sec; 1.Preheating:150~180 °C, Time:60~90sec.
- 5 ~ 0.5sec; 2.Peak Temp.:245 ± 5 °C, Duration:5 ~ 0.5sec.
- /sec. 3. Cooling Speed: 2~10 °C/sec.

Resistance to Soldering Heat Test Conditions

260 ± 5 °C, 10 ± 1 sec. Temp.:260±5 °C Time:10±1 sec

/ Packaging SPEC.

/ REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	Units/Reel 只/卷盘	Reels/Inner Box 卷盘/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Reel	Inner Box 盒	Outer Box 箱